1.	Name of Course					Electronics I				
2.	Course Code					JELT1013				
		s = the f	irst dig	it ident	ify leve	ubject is offered., JELT = the remaining three alphabets identify the el of study; in this case undergraduate level, 101 3 = the second and identify credit value or credit hours				
3.	Name(s) of academic staff					To be Assigned				
4.	Rationale for the inclusion of th programme	e cour	se/mo	odule ii	n the	Knowledge of basic electronic is essential in in both electrical and electronics engineering. Moreover, acquiring knowledge in properties of electronics components such as diodes and transistors enable engineer to design electronics circuits.				
5.	Semester and Year offered					Year 1, Semester 1				
6.	Total Student Learning Time (SLT)	Face to Face			!	Total Guided and Independent Learning				
	L = Lecture T = Tutorial P = Practical	L	Т	Р	IS	Total Guided and Independent Learning = 120				
	IS = Independent Study	42	7	6	65					
7.	Credit Value 3.0									
	Lecture: 3 hours per week x 14 weeks Tutorial: 1 hour per week x 7 weeks Practical: 2 hours x 3 weeks									
8.	Prerequisite (if any)					None				
9.	9. Course Objectives 1. To equip the students with the knowledge of the electronics components and their properties. Course Learning Outcomes (CLO) At the end of the semester students should be able to: CLO1: Understand the basic concept of band structure, doping and carrier transport in semiconductor; CLO2: Understand the concept and operation principles of PN junction and the diode application as a circuit element; CLO3: Understand the operation principles of BJT and its characteristics;									
10.	Transferable Skills: This course is expected the development of the de	ne and ndepe nsibility	task ndentl and c	y and o arry ou	co—or	peratively;				

An ability to use software where relevant to the subject.11. Teaching-learning and assessment strategy

A variety of learning strategies are used throughout the course, including the following

- Classroom Lesson; Lecturer and power point presentation
- Tutorial session
- Student- lecturer Discussion
- Collaborative and co-operative learn;
- Independent Study.

	Assessment:		
	Course works	4	0%
	Assignment	5%	
	Tutorial	5%	
	Quizzes	5%	
	Laboratory works	10%	
	Test	15%	
	Final Examination	6	<u>0%</u>
	<u>Total</u>	<u>100</u>	<u>0%</u>
12.	Synopsis:		
			of electronics. The objective of course is to provide a strong

understanding of basic electronics devices such as diodes, transistors and their applications

13. Mode of Delivery:

Lectures;

Tutorials;

Laboratory works

CLO-PLO			2	3	4	5	
	Tool						
Marks		0-39	40-49	50-59	60-74	75-100	
Grade		(F)	(D,D+)	(C-,C,C+)	(B-,B,B+)	(A-,A,A+	
CLO1: To understand the basic concept of band structure, doping and carrier transport in semiconductor.	Assignment Tutorials Lab works Test Quizzes Examination	Fail To: - manage time and task - learn both independently and cooperatively - take responsibility and carry out	Poor To: - manage time and task - learn both independently and cooperatively - take responsibility and carry out	Satisfactory To: - manage time and task - learn both independently and cooperatively - take responsibility and carry out	Good To: - manage time and task - learn both independently and cooperatively - take responsibility and carry out	Excellent To: - manage tim and task - learn both independen and cooperative - take responsibilition and carry of	
CLO2:	Assignment	laboratory test Fail To:	laboratory test Poor To:	laboratory test Satisfactory To:	laboratory test Good To:	laboratory t	
To understand the concept and operation principles of PN junction and the diode application as a circuit element;	Tutorials Lab works Test Quizzes Examination	- manage time and task - learn both independently and cooperatively - take responsibility and carry out laboratory test Fail To:	- manage time and task - learn both independently and cooperatively - take responsibility and carry out laboratory test	- manage time and task - learn both independently and cooperatively - take responsibility and carry out laboratory test	- manage time and task - learn both independently and cooperatively - take responsibility and carry out laboratory test	- manage tim and task - learn both independen and cooperative - take responsibility and carry of laboratory t	
To understand the operation principles of BJT and its characteristics;	Assignment Tutorials Lab works Test Quizzes Examination	- manage time and task - learn both independently and cooperatively - take responsibility and carry out	- manage time and task - learn both independently and cooperatively - take responsibility and carry out	- manage time and task - learn both independently and cooperatively - take responsibility and carry out	- manage time and task - learn both independently and cooperatively - take responsibility and carry out	- manage tim and task - learn both independen and cooperative - take responsibilit and carry ou	

15.	5. Mapping of the Programme Objectives to the Programme Learning Outcomes											
	Programme Learning Outcomes (PLO) Programme Objectives (PO)	PLO1: Ability to acquire and apply knowledge of science and engineering fundamentals.	PLO2: Acquired in-depth technical competence in electronics engineering discipline.	PLO3: Ability to undertake problem identification, formulation and solution;	PLO4: Ability to utilise systems approach to design and evaluate operational performance.	PLO5: Understanding of the principles of design for sustainable development;	PLO6: Understanding of professional and ethical responsibilities and commitment to them.	PLO7: Ability to communicate effectively, not only with engineers but also with the community at large.	PLO8: Ability to function effectively as an individual and in a group with the capacity to be a leader or manager;	PLO9: Understanding of the social, cultural, global and environmental responsibilities of a professional engineer	PLO10:Recognising the need to undertake lifelong learning, and possessing/acquiring the capacity to do so	PLO11: Ability become entrepreneur
	PEO1: To produce graduates with excellent knowledge and competency in Electrical and Electronics Engineering;	√	√	u 4	√	√	L C	L 0	а в	L 0	u =	<u> </u>
	PEO2: To produce graduates with professional, generic attributes to meet the present and future global demands.											
	PEO3: To produce graduates with Islamic humanistic values and reinvention skills to meet the requirement of a dynamic											
	environment. These skills include Civil Intelligence, Moral Intelligence, Self-Reliance and Communication Skills;											

16.												
16.	Programme Learning Outcomes (PLO)	_	Il competence in					effectively, not only ne community at large.	tively as an individual ty to be a leader or	icial, cultural, global ities of a professional	o undertake lifelong iring the capacity to do	reneur
	Course Learning Outcome (CLO)	PLO1: Ability to acquire and apply knowledge of science and engineering fundamentals.	PLO2: Acquired in-depth technical competence in electronics engineering discipline.	PLO3: Ability to undertake problem identification, formulation and solution;	PLO4: Ability to utilise systems approach to design and evaluate operational performance.	PLO5: Understanding of the principles of design for sustainable development;	PLO6: Understanding of professional and ethical responsibilities and commitment to them.	PLO7: Ability to communicate effectively, not only with engineers but also with the community at large.	PLO8: Ability to function effectively as an individual and in a group with the capacity to be a leader or manager;	PLO9: Understanding of the social, cultural, global and environmental responsibilities of a professional engineer	PLO10: Recognising the need to undertake lifelong learning, and possessing/acquiring the capacity to do so	PLO11: Ability become entrepreneur
	CLO1: To understand the basic concept of band structure, doping and carrier transport in semiconductor.	✓	√		√	√						
	CLO2: To understand the concept and operation principles of PN junction and the diode application as a circuit element;	✓	√		✓	√						
	CLO3: To understand the operation principles of BJT and its characteristics;	√	✓		√	✓						

D-4-			SL	T (Hour)		
Detai	IIS	L	Т	Р	IS	Total
	Introduction					
1	Fundamentals of Semiconductor Devices					
Topic	Nature of Atom, Energy-band in semiconductors	3	-	-	10	13
ř	Electrons and holes in an intrinsic semiconductor					
	P and N doping, impurity level,					
	Transport phenomena in semiconductor					
	P-N Junction as a Circuit Element					
	Creating the <i>pn</i> Junction					
7	Basic Diode Operation					
oj.	The Diode Current Equation	6	1	_	10	17
힏	Breakdown		_			
Topic 2	Temperature Effects					
	Identifying Forward- and Reverse-Bias Modes					
	• pn Junction Capacitance				10	
	Diode Circuits					
	The Diode as a Nonlinear Device					
	AC and DC resistance					
	 Analysis of DC Circuits Containing Diodes 					
	The Load Line					
	Elementary Power Supplies					
Topic3	Half-Wave and Full-Wave Rectifiers	_		-		
o	Capacitive Filtering	des 9 2	-	12	23	
-	Full-Wave Rectification					
	Voltage Multipliers					
	Elementary Voltage Regulation					
	The Zener-Diode Voltage Regulator These Tension Little and Given it Deputations					
	Three-Terminal Integrated-Circuit Regulators Diodo Timos, Potings, and Specifications					
	Diode Types, Ratings, and Specifications Dower Supply Companent Specifications					
	Power Supply Component Specifications		1	I		

	Bipolar Junction Transistor					
Topic4	 Theory of BJT Operation I_{CBO} Reverse Current Common-Base Characteristics Common-Base Input Characteristics Common-Base Output Characteristics Breakdown Common-Emitter Characteristics I_{CEO} and Beta Common-Emitter Input Characteristics Common-Emitter Output Characteristics Common-Collector Characteristics Bias Circuits 	9	1	-	10	20
Topic 5	 Common-Base Bias Circuit Common-Collector Bias Circuit Design Considerations CB Bias Design CE Bias Design CC Bias Design The BJT Inverter (Transistor Switch) Inverter Design The Transistor as a Switch Transistor Types, Ratings, and Specifications Transistor Curve Tracer Transistor Amplifier Amplifier Characteristics Input Resistance Voltage Gain Current Gain Output Resistance Power Gain The Voltage Gain Formula 	9	2		13	24
Topic 6	 Amplifier Models Source Resistance Load Resistance Inverting and Noninverting Amplification Differential Amplifiers Interstage Loading Multistage Amplifiers. 	6	1	-	10	17

	Practical	 Diode Circuits Transistor Circuits BJT Transistor Amplifier 	-	-	6	-	6		
		Total SLT(Hour)	42	7	6	65	120		
18.	Main	references supporting the course							
	1.	Theodore F. Bogart, Jeffrey S. Beasley, Guillermo Rico, "Electronic D	evices and	Circuit The	eory", 6/E	, Prentic	e Hall		
	2009.								
	Additional references supporting the course								
19.	19. Other additional information								
	All materials will be available to the students in the library.								